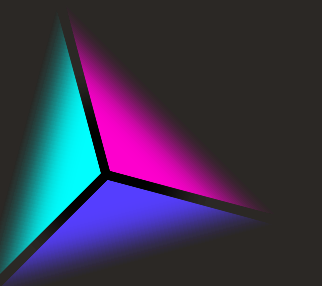




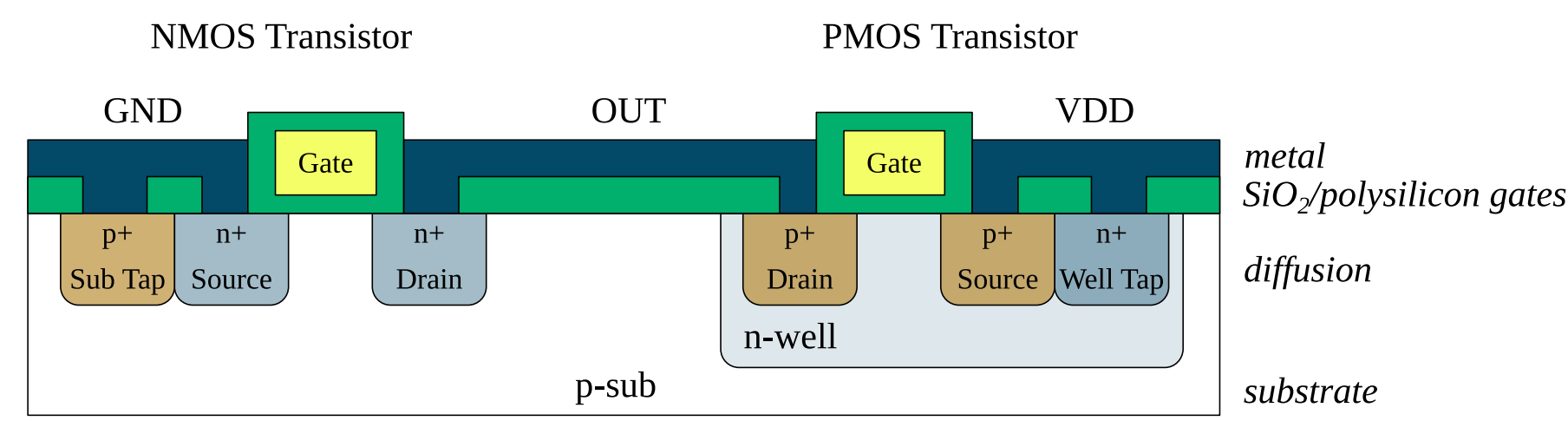
Using Voters May Lead to Secret Leakage



Motivation

- Security of many digital devices strongly depends on a secret value stored in them
- New attacks are invented continuously
 - it is important to analyze even potential threats to mitigate device vulnerability during its lifetime
 - yet unexplored properties of CMOS may lead to security threats

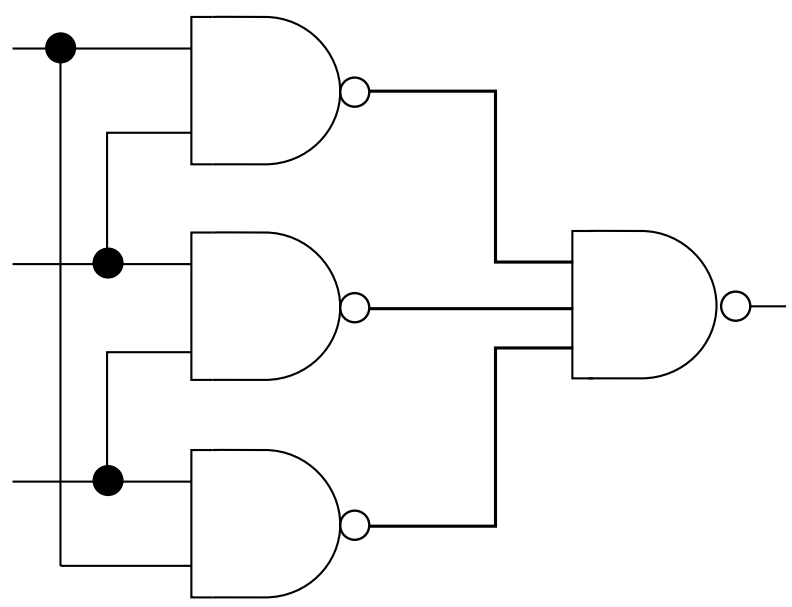
Photoelectric Laser Stimulation



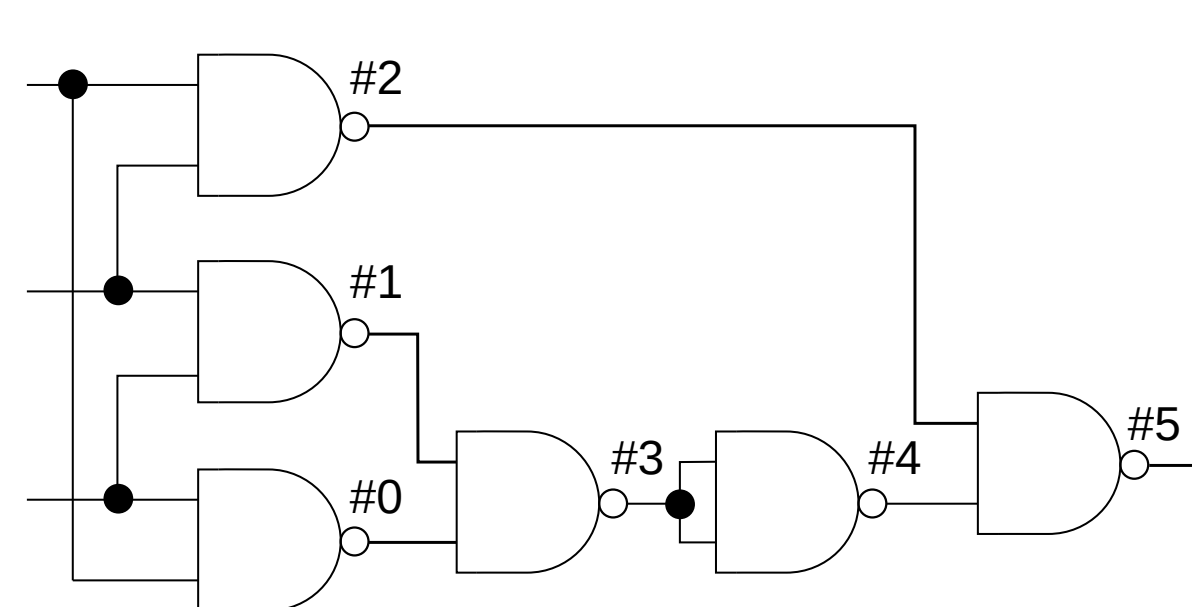
CMOS cross-section – the PN junctions

The laser beam passing through silicon creates, as a result of energy absorption, electron-hole pairs along its path, generating the *Optical Beam Induced Current* (OBIC) along PN junctions.

Conventional Majority Voter



NAND-based majority voter



Majority voter mapped to 2-input NAND gates

Security-reliability interplay research:

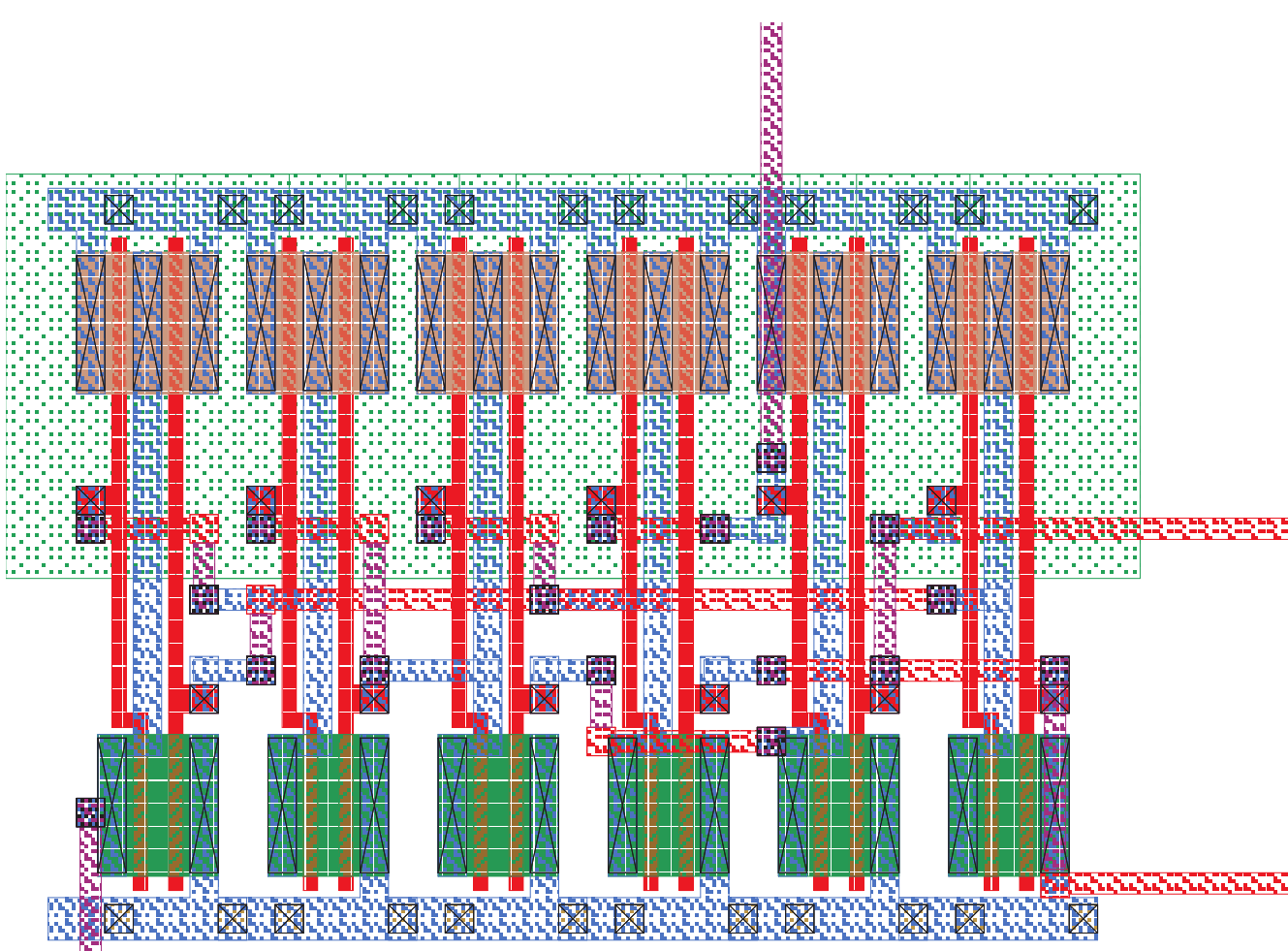
- is circuit security influenced by voter – yet unknown threats?
- is voter side-channel emission influenced by input data?

Contribution: Majority Voter as the Amplifier

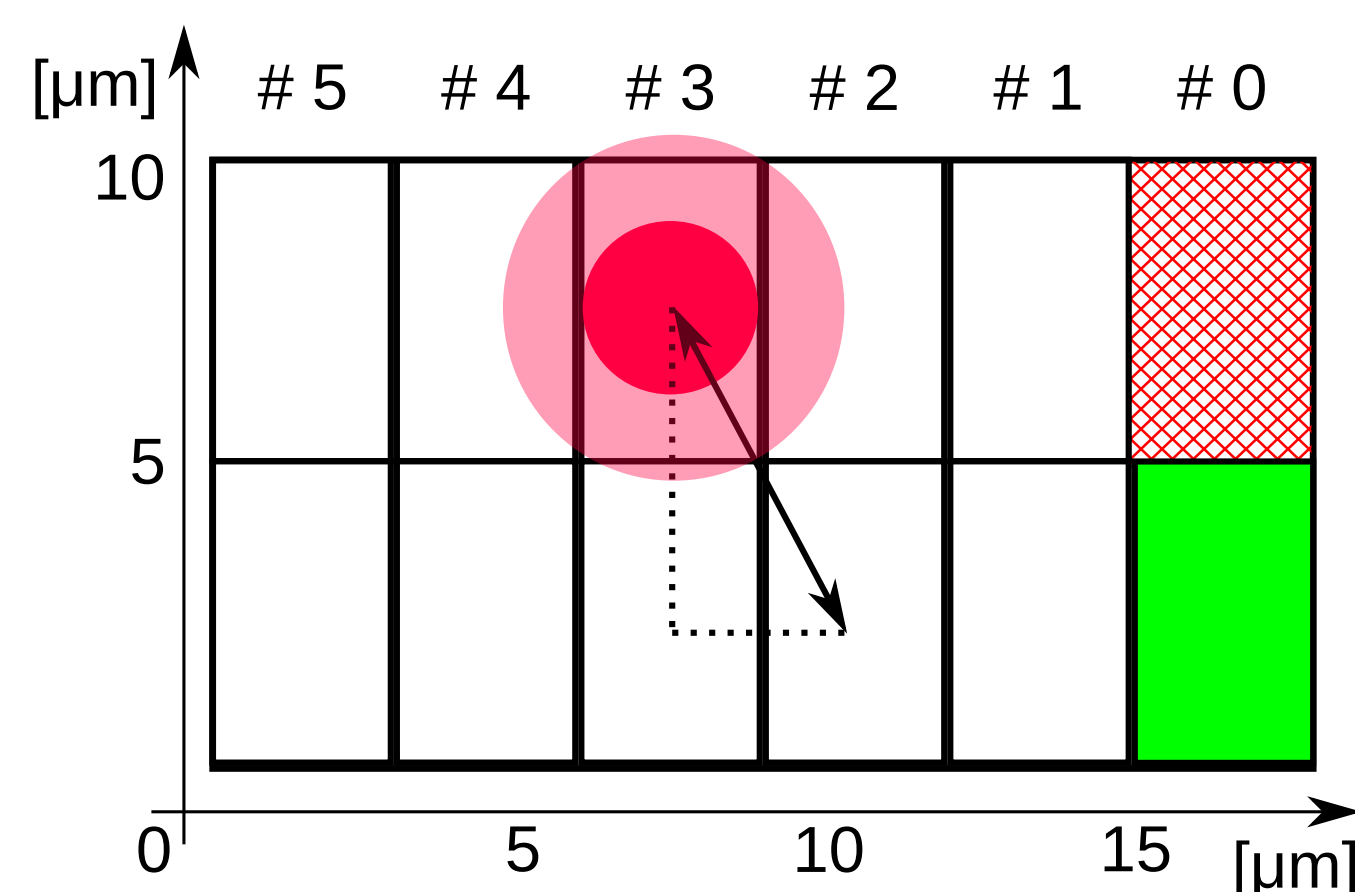
It is possible to deduce voter's input value by combining circuit illumination (by a laser) and side channel emission measurement:

- The voter size for conventional technologies, e.g. for 180nm (and also for sub-100nm processes), is large enough for precise laser-beam targeting into the voter area only
- The voter depends on a single logic value represented by multiple bits (at all its inputs): the voter may be understood as the physical amplifier of the (side channel) emissions related to the single logic value
- The majority voter is designed to mask errors → if the voter is affected by fault injection, the voter's output tends to remain stable → fault injection side-effects tend to be localized to the voter area only

Experiment Setup and Replicability



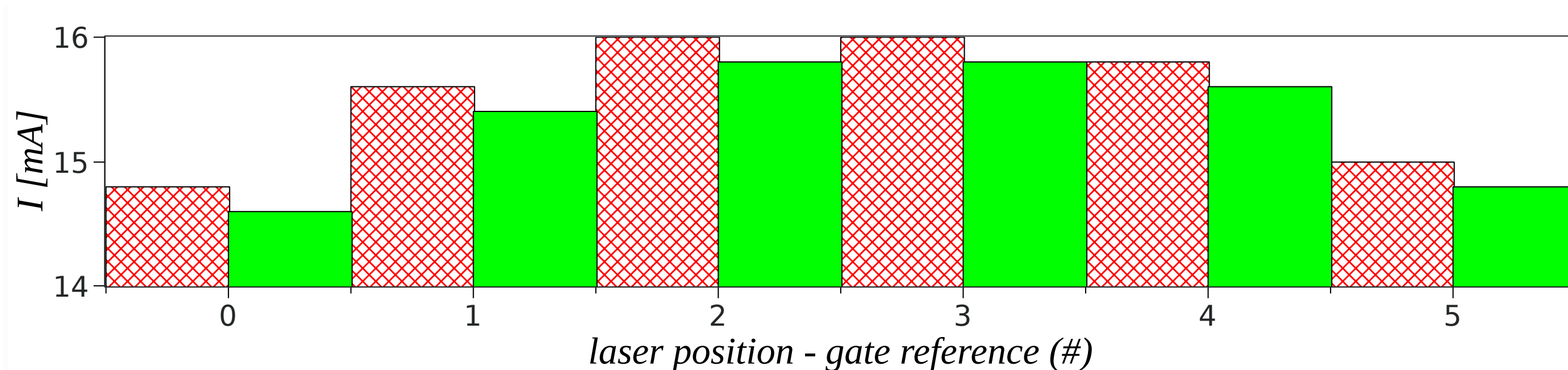
Voter layout produced by Magic
Area: $10 \times 18 \mu\text{m}$ → easy to target by a laser beam



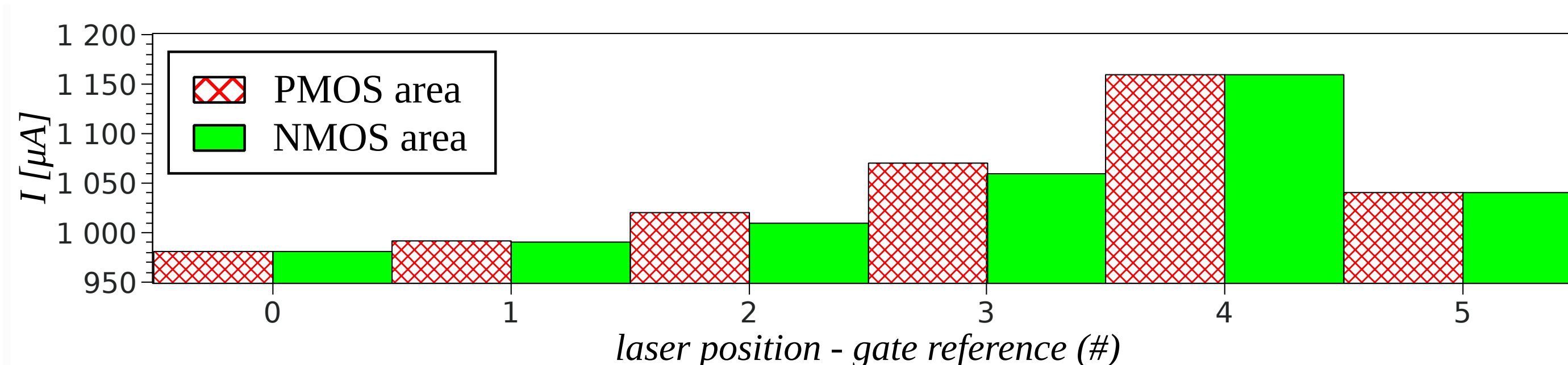
Voter area partitioning
(PMOS: red; NMOS: green)
and laser beam position

- SPICE models for *pulsed photoelectric laser stimulation* (PLS) of NMOS/PMOS based on work of Sarafianos et al.
 - Available at the DDD Research Group website
(<http://ddd.fit.cvut.cz/prj/MajVoterPLS>)
- The open tools: *digital synthesis flow* – Qflow, Magic, ngSPICE
- TSMC180 nm open standard cell provided by Oklahoma State University

Results



The current peaks induced by a PLS in a voter circuit depending on the laser beam position: average for voter all-1 and all-0 inputs is shown



The difference in current peaks induced by PLS targeting the voter with all-1 and all-0 inputs depending on the laser beam position

Future Work

- Measurements on real devices should be performed to confirm the severity of the reported threat
- The influence of voter architectures should be studied
- Data dependence of CMOS under PLS should be studied in general (Work-in-Progress)

Conclusions

- The power trace imprint of the conventional voter under PLS is correlated with processed data
 - **we identified the potential threat endangering the security of CMOS circuits employing voters**
- Our work is completely replicable: open tools were used, developed models and related resources were released under BSD-like license

If a voter is illuminated (by a laser beam), while the activity of the circuit is suppressed (stable clock and inputs), the **side channel emissions** of the *circuit under attack* **are strongly influenced by a single logic value** at the voter inputs.

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